NSN 5962-01-352-7924

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View Online at https://aerobasegroup.com/nsn/5962-01-352-7924

| Body Length: |
|--|
| 0.640 inches |
| Body Width: |
| Between 0.300 inches and 0.420 inches |
| Body Height: |
| Between 0.045 inches and 0.090 inches |
| Maximum Power Dissipation Rating: |
| 1.04 watts |
| Operating Tempurature Range: |
| -55.0/+125.0 degrees celsius |
| Storage Tempurature Range: |
| -65.0/+150.0 degrees celsius |
| Features Provided: |
| Electrostatic sensitive and hermetically sealed and burn in and monolithic |
| Inclosure Material: |
| Ceramic |
| Inclosure Configuration: |
| Flat pack |
| Output Logic Form: |
| Transistor-transistor logic |
| Input Circuit Pattern: |
| 14 input |
| Case Outline Source And Designator: |
| F-6 mil-m-38510 |
| Current Rating Per Characteristic: |
| 190.00 milliamperes reverse current, dc absolute |
| Terminal Surface Treatment: |
| Solder |
| Voltage Rating And Type Per Characteristic: |
| -0.3 volts power source and 7.0 volts power source |
| Capitance Rating Per Characteristic: |
| 15.00 input pascal industrial light tank stock and 12.00 output pascal industrial light tank stock |
| Time Rating Per Chacteristic: |
| 40.00 nanoseconds access |
| Memory Device Type: |
| Prom |
| Special Features: |
| Nuclear hardness critical items |
| Nuclear Hardness Critical Feature: |
| Hardened |

Test Data Document:

96906-mil-std-883 standard (includes industry or association standards, individual manufactureer standards, etc.).

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| Termin | al T | vne A | and C | uantity: |
|--------|-------|-------|-------|----------|
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24 flat leads

Shelf Life:

N/a

Unit Of Measure:

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Demilitarization:

Yes - demil/mli

Fiig:

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